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Journal:	<i>Nano Letters</i>
Manuscript ID	nl-2021-03790a
Manuscript Type:	Communication
Date Submitted by the Author:	30-Sep-2021
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Tailoring third-harmonic diffraction efficiency by hybrid modes in high-Q metasurfaces

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Abstract

Metasurfaces are versatile tools for manipulating light; however, they have received little attention as devices for efficient control of nonlinearly diffracted light. Here, we demonstrate nonlinear wavefront control through third harmonic generation (THG) beaming into diffraction orders with efficiency tuned by excitation of hybrid Mie-quasi-

bound-state-in-the-continuum (BIC) modes in a silicon metasurface. Simultaneous excitation of the high-Q collective Mie-type modes and quasi-BIC modes leads to their hybridization and results in a local electric field redistribution. We probe the hybrid mode by measuring far-field patterns of THG and observe the strong switching between (0,-1) and (-1,0) THG diffraction orders from 1:6 for off-resonant excitation to 129:1 for the hybrid mode excitation, showing tremendous contrast in controlling the nonlinear diffraction patterns. Our results pave the way to the realization of metasurfaces for novel light sources, telecommunications and quantum photonics.

Keywords

Third-harmonic diffraction, all-dielectric metasurface, high-Q metasurface, wavefront control, hybrid mode, bound states in the continuum

When light interacts with a periodic structure with a pitch larger than the wavelength, light diffraction occurs. Taking into account the nonlinear interactions of light with media, a wide class of phenomena associated with nonlinear diffraction of light opens up. Nonlinear diffraction was originally reported for second-harmonic generation (SHG) in systems with periodic spatial modulation of the quadratic susceptibility $\chi^{(2)}$.¹ Nonlinear diffraction of SHG and THG was further demonstrated for various periodic systems including 2D²⁻⁴ and 3D nonlinear photonic crystals.^{5,6} In these systems, second or third harmonics were generated efficiently as the nonlinear Bragg law was fulfilled at the quasi-phase matching condition.

Diffraction is also actively studied in metasurfaces, 2D arrays of subwavelength nanostructures which allow one to manipulate the phase, amplitude and polarization of transmitted or reflected light by engineering the constituent elements (i.e. meta-atoms).⁷ On-demand control of the diffraction efficiency has been demonstrated through specifically-designed spatial phase gradients realized for both plasmonic^{8,9} and dielectric metasurfaces.^{7,10-13}

The use of materials with large nonlinear susceptibilities expands the operation scope

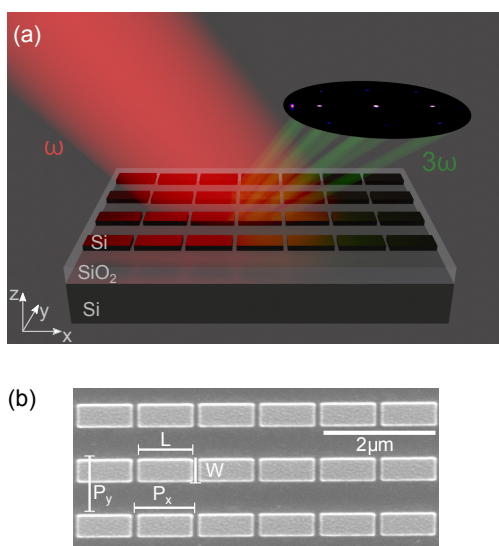
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3 of metasurfaces to the nonlinear signals. The employment of materials with high-refractive
4 index¹⁴ for metasurfaces further boosts the nonlinear-optical effects in visible and near-IR
5 ranges due to the strong local field enhancement inside the nanoresonators.^{15–21} Moreover,
6 metasurfaces allow one to control the nonlinear wavefront^{22–24} and, in particular, the non-
7 linear diffraction^{25–28} through size, shape and orientation engineering of meta-atoms even in
8 the absence of phase matching.

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15 Nonlinear diffraction in metasurfaces strongly depends on the local field distribution,
16 which is controlled through resonant modes, in particular, Mie-type resonances of individual
17 meta-atoms^{15,29} or bound states in the continuum (BIC) resonances.^{30–33} Collective reso-
18 nances of many adjacent meta-atoms give an additional boost of electric field localization^{34,35}
19 and leads to the appearance of Fano lineshapes^{36,37} due to the interference of the narrow
20 (high- Q) lattice resonance with broad spectrum paving the way to new functionalities for
21 wavefront manipulations, nonlinear diffraction control and light–matter interactions.

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29 Here, we realize an all-dielectric metasurface supporting hybrid Mie–quasi-BIC modes at
30 telecommunication wavelengths and demonstrate its capability to control the third-harmonic
31 (TH) diffraction through the switching between TH diffraction orders. The local electric field
32 enhancement at the wavelength close to 1554 nm is obtained by breaking the translation
33 invariance of a waveguide array; this leads to the excitation of hybrid Mie–quasi-BIC modes,
34 which result in strong THG. By varying the incident pump beam angle, we demonstrate the
35 modification of the local electric field in the meta-atoms leading to the switching between
36 THG diffraction orders.

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45 The studied metasurface is a 2D array of nominally identical rectangular silicon cuboids.^{38,39}
46 Because of the high refractive index, negligible absorption and large third-order susceptibil-
47 ity of silicon at telecommunication wavelengths, the metasurface can significantly enhance
48 the nonlinear optical effects under resonant excitation. The system was designed as a square
49 array of cuboids with an aspect ratio of approximately 2:1 and similar periods along the two
50 orthogonal in-plane axes to realize the high- Q collective resonances⁴⁰ (Figure 1a, 1b). The
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3 elongated shape of nanoresonators plays a key role in the dependence of the metasurface
4 response on the direction of incident linear polarization.³⁸ The use of laser radiation at the
5 wavelength of 1554 nm as the pump leads to THG at the wavelength of 517 nm for which the
6 metasurface itself is a diffraction grating. The emitted THG signal is diffracted in a square
7 pattern with nine equidistant diffraction orders (see Figure 1a and 3a).
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31 **Figure 1.** (a) Schematic illustration of our THG experiment. (b) Scanning electron mi-
32 croscopy image of the metasurface. $P_x = 1065$ nm, $P_y = 1060$ nm, $L = 940$ nm, $W = 428$
33 nm.
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36 The metasurface was fabricated out of the silicon-on-insulator (SOI) wafer by electron-
37 beam lithography and reactive-ion etching (see Methods). The thickness of the top silicon
38 layer was 125 nm and the thickness of the buried SiO_2 layer of the SOI wafer was $2 \mu\text{m}$. The
39 metasurface spans a square area of $25 \times 25 \mu\text{m}^2$. The periods of cuboids along the x and y
40 axes were almost identical being 1065 nm and 1060 nm, respectively (see Figure 1b). The
41 length and the width of the cuboids were chosen to be 940 nm and 428 nm, respectively.³⁹
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48 Such metasurface features both Mie-type modes and a quasi-BIC mode which hybridize
49 at the condition of spectral overlapping. To study in detail the angular dispersion of these
50 modes, we carried out angle-resolved calculations of the transmittance spectra for two or-
51 thogonal exciting polarizations, across and along the long side of the cuboid. The angle of
52 incidence was tilted away from the normal in a S-polarized configuration to maintain the
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3 exciting field parallel to the metasurface plane. The sketches of polarizations, cross-S and
4 co-S, with denoted angles of incidence, θ_1 and θ_2 , are represented in Figure 2a, 2b. In cross-S
5 polarization, for normal incidence around 1585 nm we observe a narrow Fano feature, which
6 is associated with the interference of a Mie-type magnetic quadrupole (MQ) mode with a
7 broad Fabry–Pérot resonance inside the SiO₂ substrate (see Figure 2c). Due to the odd
8 number of local electric field nodes along the long side of cuboid, the MQ mode has odd
9 parity and mirror symmetry and can be resolved at normal incidence. The magnetic dipole
10 (MD) mode has even parity, an even number of local electric field nodes along the long side
11 of the cuboids and cannot be resolved at normal incidence since its excitation is symmetry-
12 forbidden.⁴¹ For the aforementioned symmetry considerations, to excite the MD mode it is
13 necessary to introduce a phase retardation inside the volume of the cuboids by changing
14 the illumination angle.⁴² The same symmetry rules are applied to the excitation of the MD
15 mode in the co-S polarization, at which the MQ mode cannot be excited at any incident
16 angle. The corresponding local fields distributions for cross-S and co-S polarizations at 4°
17 illumination are shown on Figure S8 and Figure S9. By illuminating the metasurface at both
18 cross-S and co-S polarizations, the Rayleigh anomalies and the broad Fabry–Pérot resonance
19 are clearly resolved in the transmission spectra (see Supporting Information, Sections 2 and
20 3). More importantly, MQ and MD modes hybridize with the quasi-BIC mode emerging
21 at larger incident angles. The excitation of the quasi-BIC mode occurs by analogy with its
22 excitation in metasurfaces consisting in an array of rectangular waveguides. The principle
23 of excitation of the quasi-BIC mode in such metasurface and the corresponding local field
24 distributions are shown in Figure 2(e–h) and Figures S5–S7. As a result, the emergence of
25 a hybrid mode leads to the redistribution of local electric fields in cuboids.

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49 The quasi-BIC mode is characterized by the presence of dominant $|H_z|$ and $|E_x|$ compo-
50 nents, thus the incident pump field must match those components (see Figure 2(e–h)). As
51 the H_z -component of incident field remains equal to zero at cross-P and co-P polarizations,
52 the quasi-BIC mode is not excited in metasurfaces formed by cuboids (see Figure S2(c–
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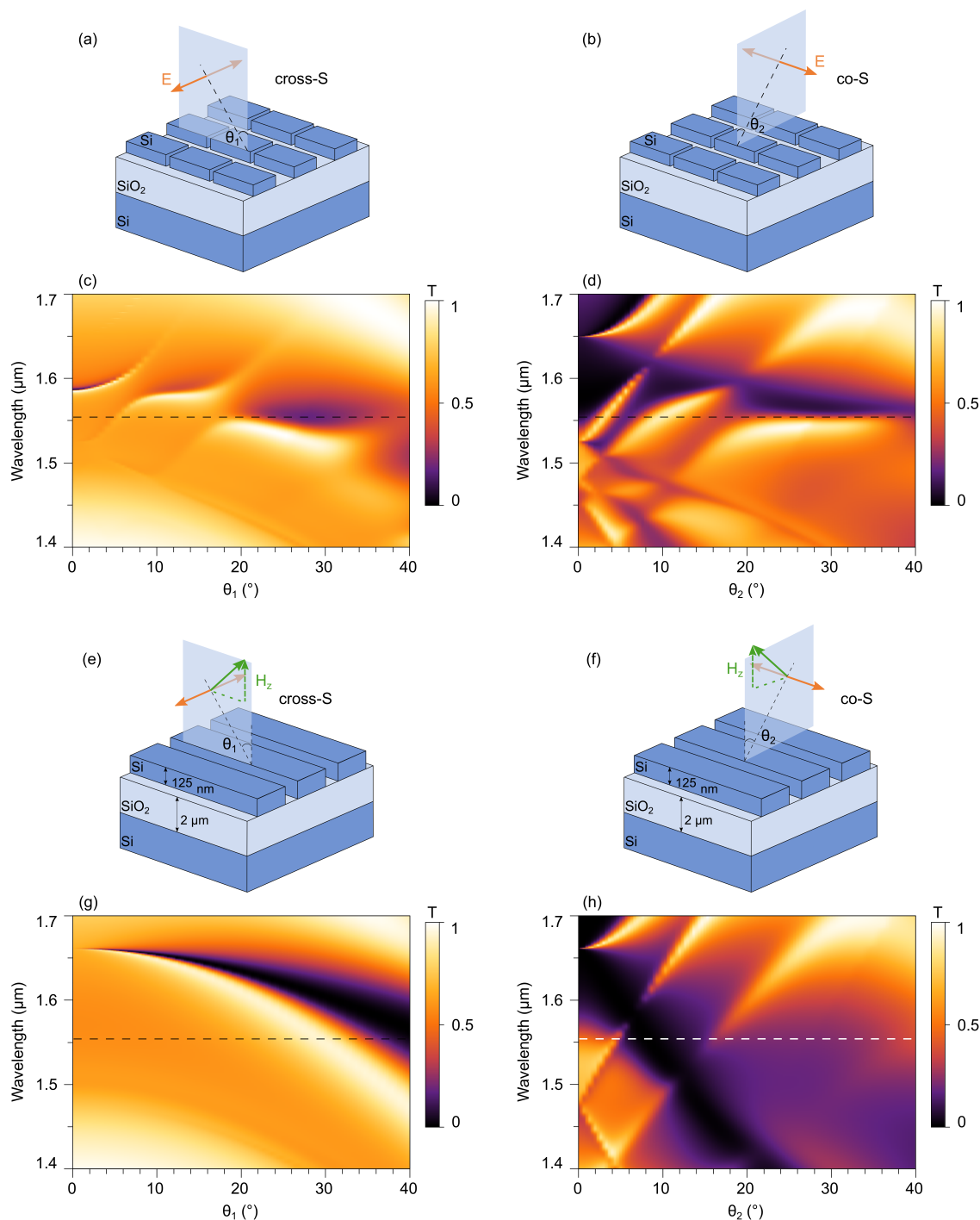


Figure 2. (a), (b) Schematic drawings of cross-S and co-S polarized excitation for metasurfaces comprising cuboids and (e), (f) for metasurfaces comprising infinite waveguides. (c), (d) Calculated transmittance as a function of the angle and wavelength of incidence for cross-S and co-S polarization for metasurfaces comprising cuboids and (g), (h) for metasurfaces comprising infinite waveguides. The dashed lines indicate the exciting wavelength of $\lambda = 1554 \text{ nm}$.

d)) and rectangular waveguides (see Figure S5(e-f)) and the redistribution of local electric fields inside the cuboids is not observed (see Figure S10). To excite the quasi-BIC mode around 1550 nm and to probe its hybridization with the MQ and MD Mie-type modes in the nonlinear regime we further focus on experiments with the cross-S and co-S polarizations.

The metasurface is illuminated by a collimated femtosecond laser beam at different incident angles in cross-S and co-S polarizations. The angle of incidence on the sample is controlled by the movement of the loosely focused beam across the back focal plane of the objective lens (see section BFP imaging of THG diffraction orders in Methods and Figure S1). The output THG signal is collected by the same objective in the backscattering configuration. The THG diffraction pattern is imaged by a cooled CCD camera. The details of the experimental setup are provided in the Methods Section. Each diffraction order is integrated over the same spatial area and the signal from the substrate is subtracted. A set of THG diffraction patterns corresponding to different incident angles is obtained. The typical patterns of THG signals that correspond to (-1,0), (1,0), (0,1) and (0,-1) diffraction orders for cross-S polarization at 0° and 22° of incidence are shown in Figure 3a, 3b, where the areas of integration are highlighted by dashed green and orange circles, respectively. The (1,0) diffraction order falls outside the objective collection range at the angle of incidence of 22° due to the angular shift of the THG diffraction map. The integrated signals from these maps are represented in Figure 3c and the switching from ($\pm 1,0$) THG diffraction orders for normal incidence to (0, ± 1) orders for $\theta = 22^\circ$ is clearly seen.

The overall THG is retrieved as the sum of all detected diffraction orders. Its dependence on the angle of incidence is shown in Figure 4a, 4d in case of cross-S and co-S polarizations, respectively. The strong enhancements of THG intensities are clearly observed at certain angles for both polarizations. The maximum TH emission of 173 fW is achieved at approximately 20° for cross-S, and the maximum of 1.17 pW is achieved at $\theta = 28^\circ$ for co-S. These experimental THG enhancements are attributed to the local electric field enhancement inside the silicon cuboids at the wavelengths of the hybrid Mie-quasi BIC mode excitation.

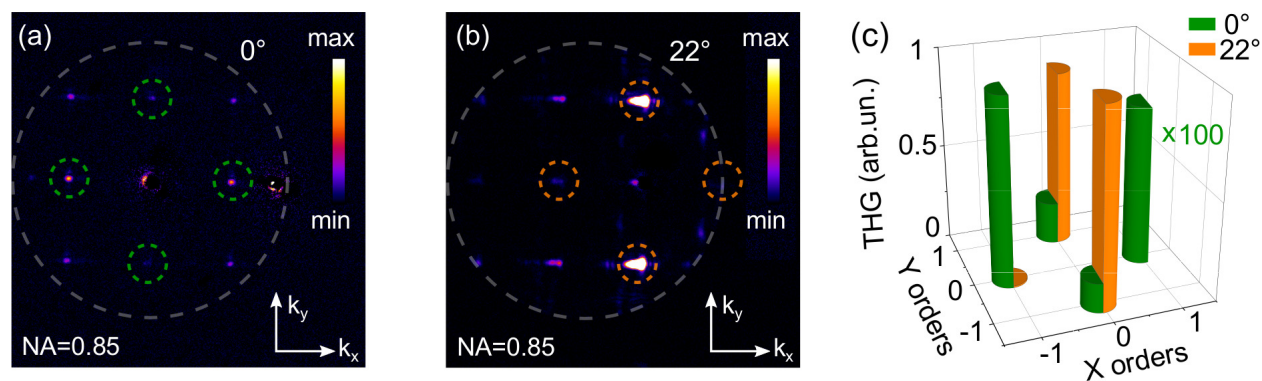


Figure 3. BFP images of the THG diffraction patterns at angles of incidence of 0° (a) and 22° (b) for cross-S exciting polarization. The large dashed grey circles denote the NA of the collecting objective. The small dashed green and orange circles denote the areas where the THG signal was integrated. (c) Power of the THG diffraction orders in a (green) and b (orange). THG at 0° (green bars) is magnified by 100 times.

We have performed numerical simulations and integrated the electric field within the volume of the cuboids. A detailed description of the simulations is given in the Supporting Information, Section 6. We plot in Figure 4a, 4d the quantity:

$$I_{\text{avg}} \propto \int_{\text{volume}} \int_{\text{pulse}} |\mathbf{E}(\mathbf{r}, \nu)|^6 dV d\nu, \quad (1)$$

where $\mathbf{E}(\mathbf{r}, \nu)$ is the calculated electric field distribution and the integrals are performed over the volume of the cuboid and over the spectrum of the laser pulse. Taking into account the electric fields only at fundamental frequency we have a good agreement between the experimental and simulated resonant peak angles for THG. The field enhancements are visualized in local electric field distributions in the xy -plane through the middle of the cuboid at normal incidence and at the angles corresponding to maximum signals, at 22° for cross-S and at 28° for co-S, see Figures 4b, 4c, 4e, 4f. These electric field maps show the electric field redistribution and their enhancement with respect to normal incidence by a factor of up to 7 and 2.5, respectively.

The studied metasurface is a system for efficient THG and, at the same time, a diffraction grating for the THG light. Typical experimentally obtained THG diffraction pat-

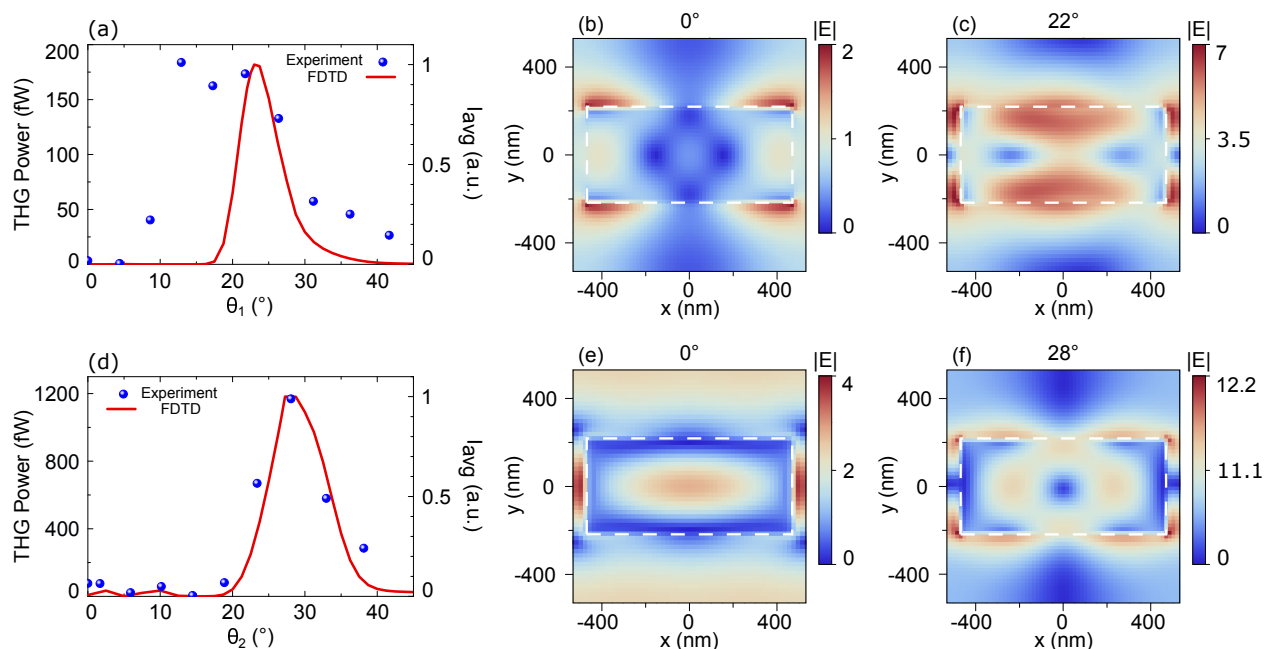


Figure 4. (a), (d) Experimental THG signal as a function of the angle of incidence and THG response evaluated from FDTD simulations in cross-S and co-S polarizations, respectively. (b), (c) Normalized electric field in the middle of the xy plane of the silicon cuboid at the wavelength of 1554 nm in cross-S excitation at incident angles of 0° and 22° . (e), (f) Normalized electric field in the middle of the xy plane of the silicon cuboid at the wavelength of 1554 nm in co-S excitation at incident angles of 0° and 28° . Dashed white rectangles indicate the borders of cuboids.

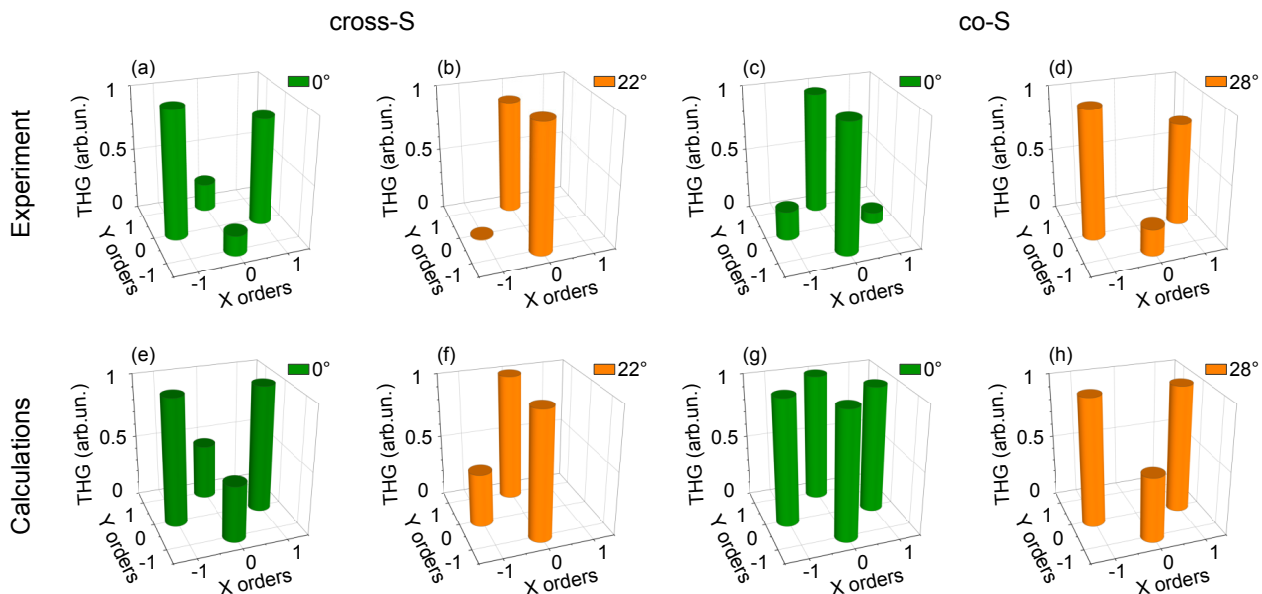


Figure 5. THG power distribution between the diffraction orders. (a, b) Experimental and (e, f) simulated power distribution for cross-S polarization at incident angles of 0° and 22° . (c, d), (g, h) Same as (a, b), (e, f) for co-S polarization at incident angles of 0° and 28° .

terns are shown in Figures 3a, 3b with the 1st diffraction orders occurred at angle close to $\theta=30^\circ$ (highlighted with green circles) at the normal pump incidence, as $\text{NA} = \sin \theta = \text{THG wavelength/period} = 517 \text{ nm}/1060 \text{ nm}$. The THG diffraction pattern shifts with tilting the incident angle as it is shown in Figure 3b. As the angle of incidence is varied, the redistribution of intensity between diffraction orders is observed. Figures 5(a-d) represent the experimental THG signals at the (-1,0), (1,0), (0,1), (0,-1) diffraction orders, for both cross-S and co-S polarizations. At normal incidence and cross-S illumination, the brightest THG orders are $(\pm 1,0)$. As the angle of incidence is tilted, the ratio between the intensities of different pairs of diffraction orders changes and redistribution between diffraction orders is achieved at the condition of resonant excitation of the hybrid Mie-quasi-BIC mode at 22° , where the most intense diffraction orders are $(0,\pm 1)$ (see Figure 5b). The opposite behaviour is observed in co-S polarization, where $(0,\pm 1)$ orders are the most intense at normal incidence excitation (see Figure 5c, 5g). However, at the resonance of the hybrid mode at $\theta = 28^\circ$, $(\pm 1,0)$ orders are much brighter than $(0,\pm 1)$ ones.

The observed switching between pairs of THG diffraction orders with tilting the angle of incidence is explained by the far field emission of dipoles sources at 3ω . The dipoles mimic the hot spots of the electric field in the cuboid cross section on the middle of its height with suitable positions, amplitudes and phases taken from Figure 4b, 4c, 4e, 4f. We simulate the metasurface response by arranging the dipoles in 2D arrays that correspond to the hot spots of E_x and E_y fields. The dipoles at the THG frequency spatially coincide with the dipoles at the fundamental frequency and there is a phase shift between dipoles in the case of tilted incidence. A detailed account of how diffraction order are simulated is given in the Supporting Information, Section 7. The calculated THG diffraction orders bar diagrams are in good agreement with the experimental ones where the most intense orders for cross-S are $(\pm 1,0)$ at normal incidence and $(0,\pm 1)$ at 22° incidence (see Figure 5). All four calculated THG diffraction orders have comparable intensities with slightly larger values for $(0,\pm 1)$ orders at co-S polarization at normal incidence. The mismatch between calculations

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3 and experiment is possibly due to the fact that the model deals with point sources rather
4 than the extended sources of local field as it is shown in the electric field map in Figure
5 4e. The simulation are in excellent agreement with the experimental THG diffraction orders
6 for co-S polarization at the resonant excitation corresponding to a 28° incidence angle. It
7 can be concluded that the redistribution between THG diffraction orders with tilting angle
8 of incidence occurs due to the changes in the arrangement of the electric dipoles in the
9 metasurface caused by the excitation of the hybrid Mie–quasi-BIC mode in cross-S and co-S
10 polarizations.
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15 In summary, we experimentally demonstrate the intensity switching between THG diffrac-
16 tion orders in a high- Q resonant silicon metasurface. This phenomenon is associated with
17 the excitation of the hybrid Mie–quasi-BIC mode at oblique incidence of the laser beam
18 that results in the enhancement and the spatial redistribution of local electric fields inside
19 the elements of the metasurface. These modifications in the local electric field distributions
20 observed for two cases of incident linear polarizations lead to changes in the far-field THG
21 diffraction pattern. This correlation between near-field and far-field distributions is well de-
22 scribed by a simulation model based on local nonlinear dipole sources. Our results pave the
23 way to efficient nonlinear wavefront control by all-dielectric metasurface.
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40 Methods

41 Sample fabrication

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43 The metasurface was fabricated using a silicon-on-insulator (SOI) (001) wafer with a device
44 thickness of 125 nm and a box of $2\ \mu\text{m}$. The (110) orientation of silicon lattice was aligned
45 along the long side fabricated cuboids. The positive PMMA resist was spin-coated on the
46 SOI, which was patterned via the electron-beam lithography (EBL) to define the desired
47 patterns. During the lithographic step, different doses were used to create cuboids with
48 length of 940 nm (± 10 nm), width of 428 nm (± 10 nm) and spatial period of 1060 nm.
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3 The regular pattern in the SOI was obtained by reactive ion etching (RIE) using CF_4 as
4 etchant gas (Figure 1b). The RIE etching rate was adjusted to etch 125 nm of the Si
5 device layer and the etch depth was characterized with atomic force microscope (AFM) and
6 scanning electron microscopy (SEM). The final removal of the resist was carried out by 10
7 min of acetone and isopropanol cleaning; this wet-chemical step may leave resist residues
8 which were therefore removed by a 225 W oxygen plasma and a HF rinse (5% vol) of five
9 seconds. A more detailed description of the fabrication process is provided in Ref.[39].
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19 **BFP imaging of THG diffraction orders**

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21 We employ back focal plane (BFP) imaging in reflectance accompanied with THG microscopy
22 for measurements of THG diffraction patterns. The scheme of the experimental setup is
23 shown in Supplementary Figure S1. The radiation of a femtosecond laser (oneFive, Origami-
24 15) with the central wavelength of 1554 nm, 160 fs pulse duration and 80 MHz repetition
25 rate was loosely focused onto the BFP of the objective by a 50 cm-focal-length doublet
26 (ThorLabs, AC254-300-C-ML) to illuminate uniformly the $25 \times 25 \mu\text{m}^2$ area of the sample.
27 The 60x objective lens with NA=0.85 (Nikon, Plan Fluorite) formed a quasi collimated beam
28 with FWHM of approximately the size of the metasurface and, at the same time, collected the
29 THG signal in a backscattering configuration. A dichroic mirror (ThorLabs, DMLP950) was
30 placed before the objective to separate the fundamental beam and the nonlinear emission.
31 Sample was placed on a xyz -piezo stage facing to the incident radiation. Two confocal lenses
32 with focal lengths of 50 cm and 40 cm, respectively, were mounted in the detection path to
33 image the BFP of the objective. The second lens relayed the BFP image onto the sensor of a
34 cooled CCD camera (Andor, iKon-M). A bandpass (ThorLabs, FBH520-40) and a shortpass
35 (ThorLabs, FESH0700) filters were inserted in detection path for chromatic filtering of the
36 THG at the wavelength of 517 nm. The linear polarization of the pump beam was controlled
37 by a half wave retarder. The oblique incidence of quasi collimated beam on the sample was
38 realized by shifting laterally the loosely focused beam across the BFP of the objective.
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Supporting Information Available

Scheme of experimental setup of THG microscopy; calculations of angle-resolved transmittance spectra for cross-P and co-P polarizations; calculations of Fabry–Pérot resonance in three-layer structure Si–SiO₂–Si and Rayleigh anomalies in metasurface; calculations of angle-resolved transmittance spectra for cross-S, co-S, cross-P and co-P polarizations and local electric field localization in metasurface from infinite waveguides; calculations of local electric field localization for cross-S, co-S, cross-P and co-P polarizations in metasurface; experimental and simulated THG diffraction maps for cross-P and co-P polarizations for metasurface; description of FDTD simulations and simulations of THG diffraction maps.

Acknowledgement

The work was performed under financial support of the Russian Ministry of Education and Science (Grant No. 14.W03.31.0008, numerical calculations) and the Russian Foundation for Basic Research (Grant No. 21-52-12036, sample characterization). K.I.O. thanks MSU Quantum Technology Centre for the support. M.R.S. thanks the Russian Science Foundation (Grant No. 18-12-00475, optical measurements). A.A.F. thanks the Interdisciplinary Scientific and Educational School of Lomonosov Moscow State University «Photonic and Quantum technologies. Digital medicine». Part of the work was supported by European Commission (828890 (FET Open NARCISO), 899673 (FET Open METAFAST)); Ministero dell’Istruzione, dell’Università e della Ricerca (2017MP7F8F (PRIN project NOMEN)).

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Graphical TOC Entry

